

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- 100% EAS Guaranteed
- Green Device Available

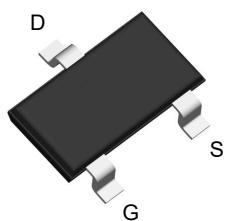
Product Summary



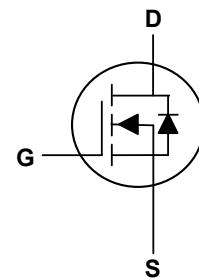
V_{DS}	100	V
I_D	5	A
$R_{DS(ON)}$ Typ (at $V_{GS}=10V$)	105	mΩ
$R_{DS(ON)}$ Typ (at $V_{GS}=4.5V$)	140	mΩ

Applications

- High Frequency Point-of-Load,Synchronous Buck Converter
- Networking DC-DC Power System
- Load Switch



SOT23-3L Top View



Absolute Maximum Ratings($T_A=25^\circ C$, unless otherwise noted)

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ¹	$I_D @ T_A=25^\circ C$	5	A
Continuous Drain Current ¹	$I_D @ T_A=70^\circ C$	3.2	A
Pulsed Drain Current ²	I_{DM}	12	A
Total Power Dissipation ⁴	P_D	2.5	W
Storage Temperature Range	T_{STG}	-55 to 150	°C
Operating Junction Temperature Range	T_J	-55 to 150	°C

Thermal Characteristics

Parameter	Symbol	Typ	Max	Unit
Thermal Resistance Junction-Ambient ¹	$R_{\theta JA}$	---	74	°C/W
Thermal Resistance Junction-Case ¹	$R_{\theta JC}$	---	80	°C/W

Electrical Characteristics ($T_J=25^\circ\text{C}$, unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}$, $I_D=250\mu\text{A}$	100	---	---	V
Static Drain-Source On-Resistance	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}}=10\text{V}$, $I_D=3\text{A}$	---	105	140	$\text{m}\Omega$
		$V_{\text{GS}}=4.5\text{V}$, $I_D=2\text{A}$	---	140	170	$\text{m}\Omega$
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{GS}}=V_{\text{DS}}$, $I_D = 250\mu\text{A}$	1.0	---	2.5	V
Drain-Source Leakage Current	I_{DSS}	$V_{\text{DS}}=100\text{V}$, $V_{\text{GS}}=0\text{V}$, $T_J=25^\circ\text{C}$	---	---	1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{\text{GS}}=\pm 20\text{V}$, $V_{\text{DS}}=0\text{V}$	---	---	± 100	nA
Total Gate Charge	Q_g	$V_{\text{DS}}=50\text{V}$, $V_{\text{GS}}=10\text{V}$, $I_D=2\text{A}$	---	18	---	nC
Gate-Source Charge	Q_{gs}		---	2.5	---	
Gate-Drain Charge	Q_{gd}		---	4	---	
Turn-On Delay Time	$T_{\text{d(on)}}$	$V_{\text{DS}}=50\text{V}$, $V_{\text{GS}}=10\text{V}$, $R_G=1.8\Omega$, $I_D=3\text{A}$	---	7.5	---	ns
Rise Time	T_r		---	6	---	
Turn-Off Delay Time	$T_{\text{d(off)}}$		---	21	---	
Fall Time	T_f		---	9	---	
Input Capacitance	C_{iss}	$V_{\text{DS}}=25\text{V}$, $V_{\text{GS}}=0\text{V}$, $f=1\text{MHz}$	---	765	---	pF
Output Capacitance	C_{oss}		---	38	---	
Reverse Transfer Capacitance	C_{rss}		---	33	---	

Drain-Source Diode Characteristics

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Diode Forward Voltage ²	V_{SD}	$V_{\text{GS}}=0\text{V}$, $I_S=3\text{A}$, $T_J=25^\circ\text{C}$	---	---	1.2	V
Reverse recovery time	t_{rr}	$I_F=3\text{A}$, $dI/dt=125\text{A}/\mu\text{s}$	---	21	---	ns
Reverse recovery charge	Q_{rr}		---	22	---	nC

Note:

- 1.The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2.The data tested by pulsed , pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$

Typical Characteristics

Figure 1: Output Characteristics

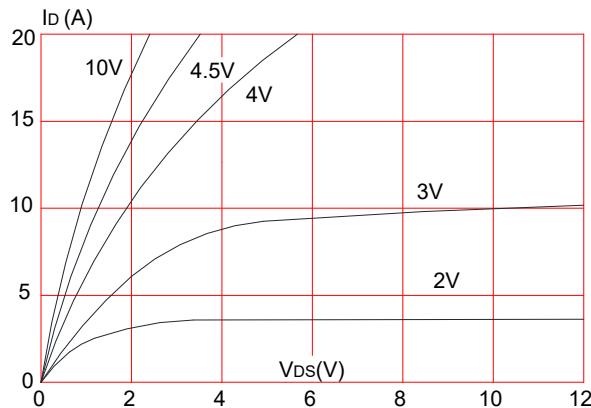


Figure 3: On-resistance vs. Drain Current

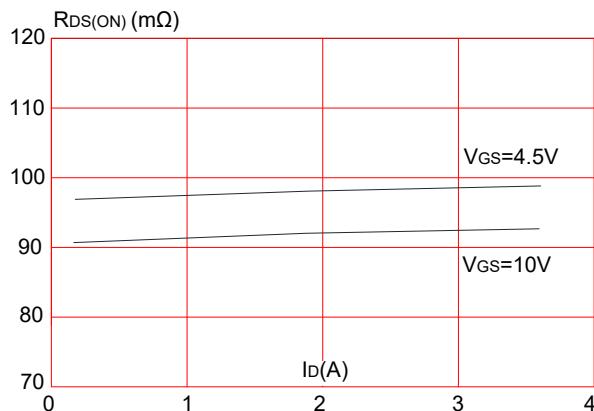


Figure 5: Gate Charge Characteristics

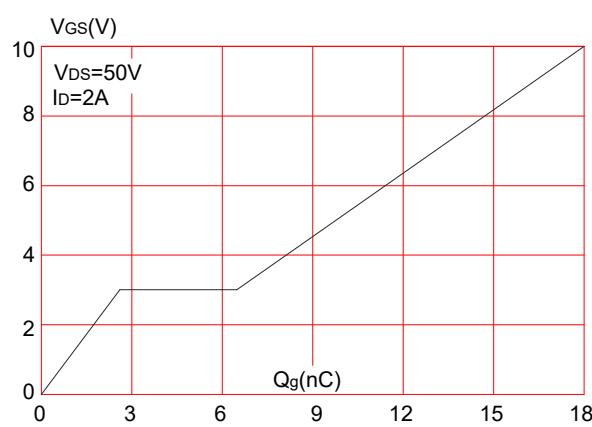


Figure 2: Typical Transfer Characteristics

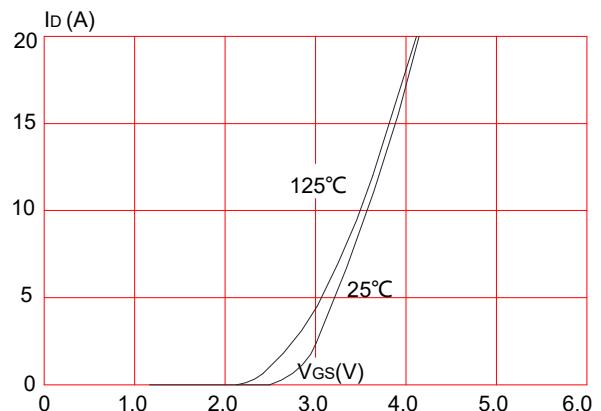


Figure 4: Body Diode Characteristics

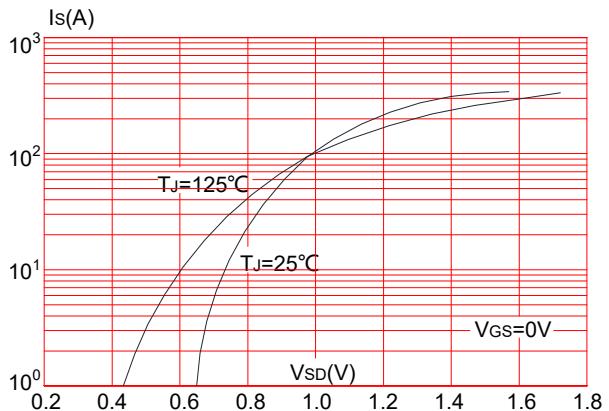


Figure 6: Capacitance Characteristics

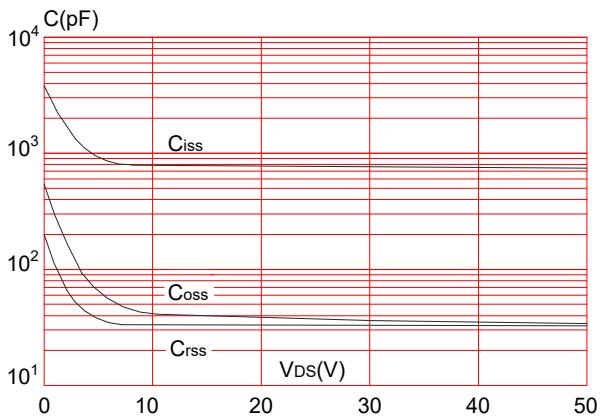


Figure 7: Normalized Breakdown Voltage vs. Junction Temperature

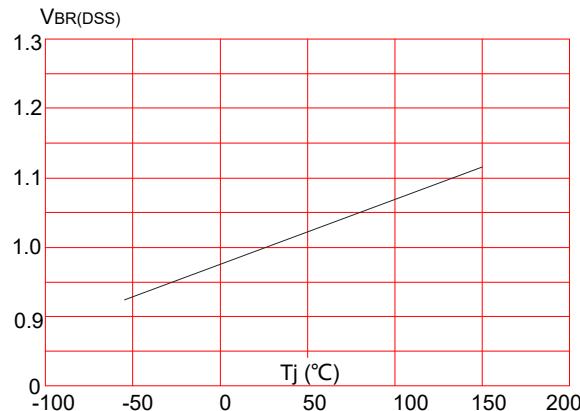


Figure 9: Maximum Safe Operating

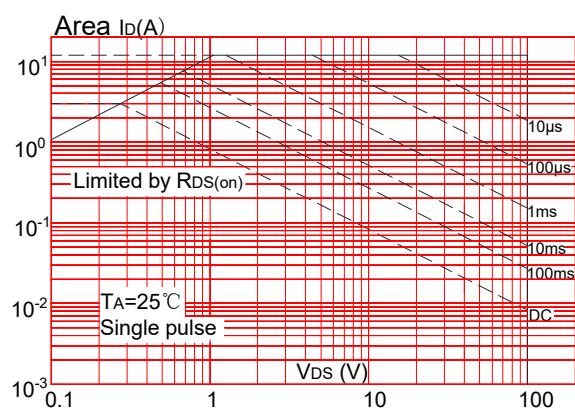


Figure 11: Maximum Effective Transient Thermal Impedance, Junction-to-Ambient

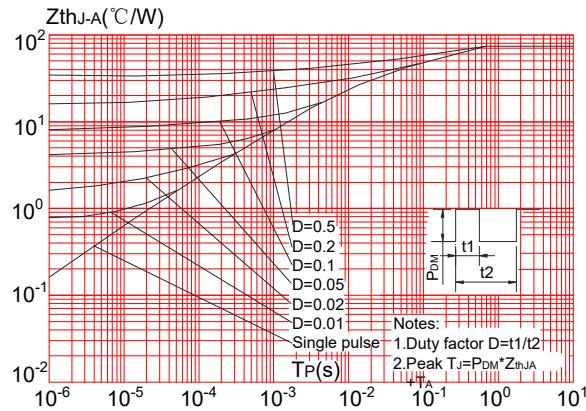


Figure 8: Normalized on Resistance vs. Junction Temperature

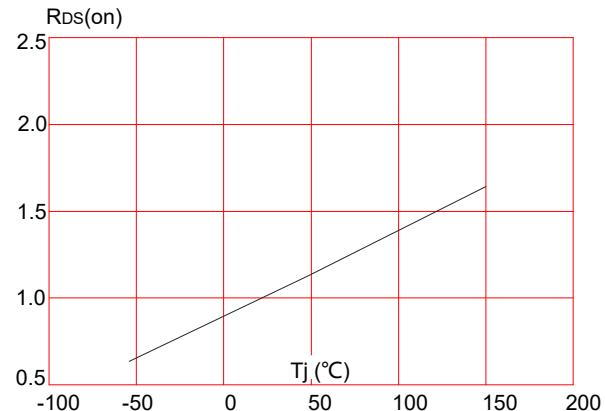
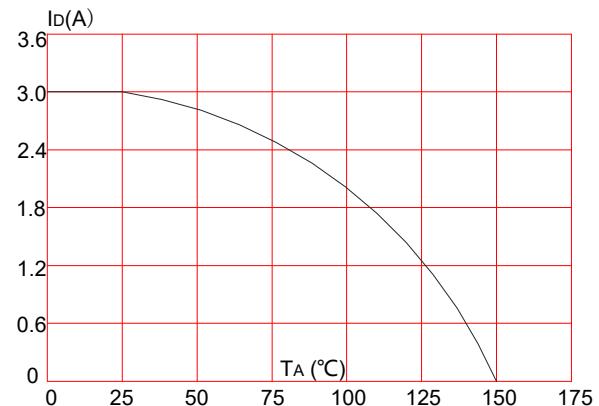
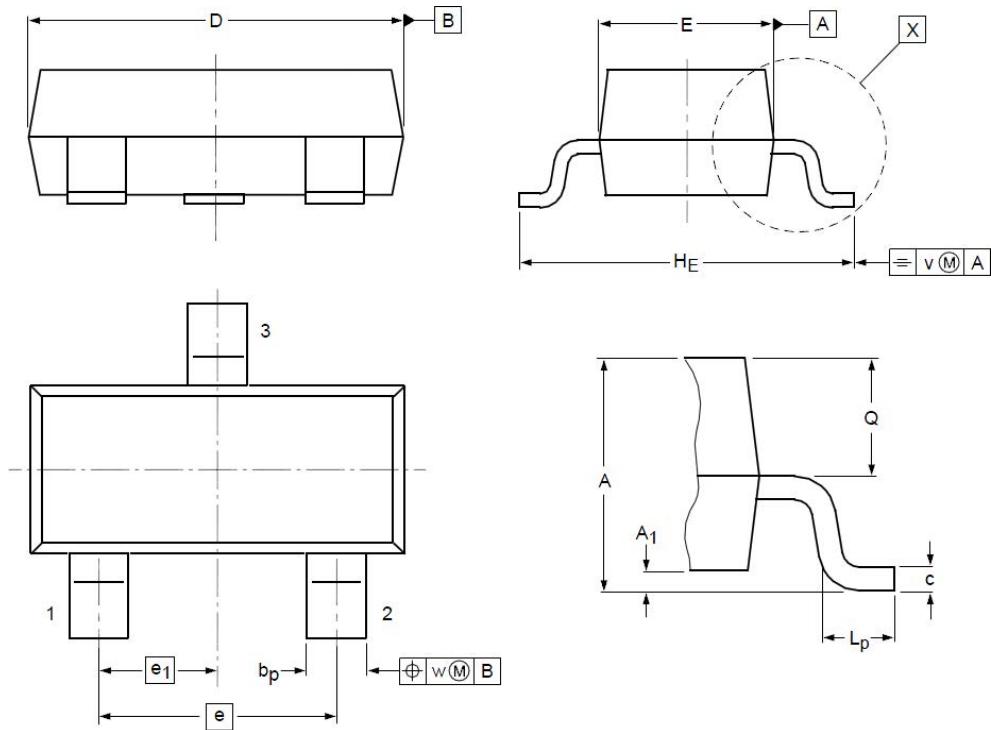


Figure 10: Maximum Continuous Drain Current vs. Ambient Temperature



SOT23-3L Package Outline Dimensions



Symbol	Dimensions (unit:mm)			Symbol	Dimensions (unit:mm)		
	Min	Typ	Max		Min	Typ	Max
A	0.90	1.07	1.25	e₁	--	0.95	--
A₁	0.01	0.05	0.10	H_E	2.50	2.80	3.00
b_P	0.30	0.40	0.50	L_P	0.30	0.45	0.60
c	0.10	0.15	0.20	Q	0.23	0.28	0.33
D	2.70	2.90	3.10	V	--	0.20	--
E	1.40	1.55	1.75	W	--	0.20	--
e	--	1.90	--				